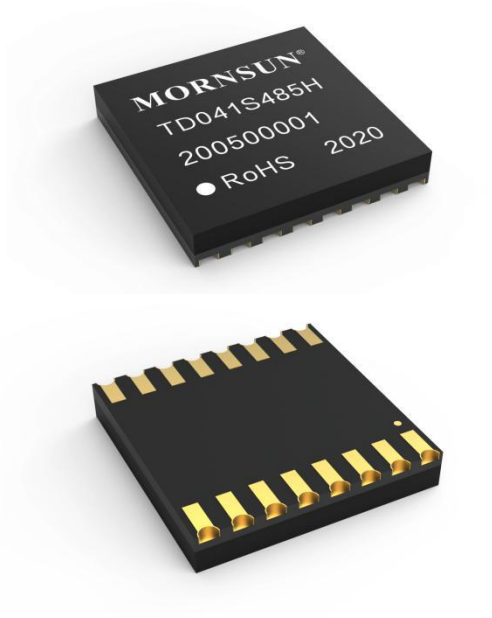
MORNSUN®

TD041S485H
DFN package isolated RS485 Transceiver

Features

- Ultra-small, ultra-thin, chip scale DFN package
- Compliant with TIA/EIA-485A standard
- I/O power supply range supports 3.3V and 5V microprocessors
- High isolation to 3750Vrms
- Bus-Pin ESD protection up to 15kV(HBM)
- Baud rate up to 20Mbps
- ＞25kV/μs CMTI
- Low communication delay
- 1/8 unit load—up to 256 nodes on a bus
- Bus fail-safe
- Bus driver short circuit protection
- Industrial operating ambient temperature range: -40℃ to +105℃
- Meet AEC-Q100 Standards
- EN62368 approval
- Moisture Sensitivity Level (MSL) 3

Package



Applications

- Industrial Automation
- Building Automation
- Smart Electricity Meter
- Remote Signal Interaction, Transmission

Functional Description

TD041S485H is a half-duplex enhanced transceiver designed for RS–485 data bus networks, which is fully compliant with TIA/EIA-485A standard and is suitable for data transmission of up to 20Mbps. Their logic side supports 3.3V and 5V logic level conversion. Receivers have an exceptionally high input impedance, which places only 1/8 of the standard load on a shared bus and up to 256 transceivers.

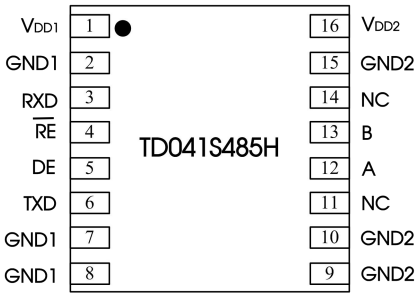
TD041S485H reliability design of A, B pin is emphasized, including driver output over current protection and enhanced ESD design. The ESD protection level of A,B pin can be up to 15KV (Human Body Model).

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Contents

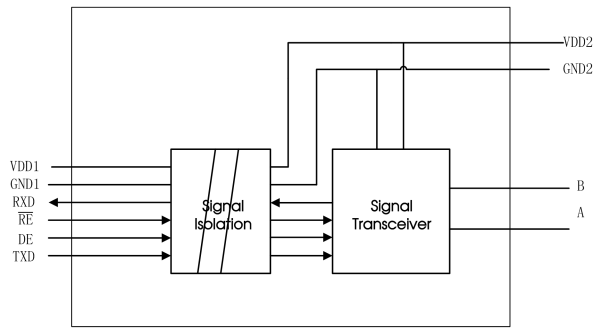
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Pin Connection



Note：All GND1 pins are internally connected;
All GND2 pins are internally connected.

Internal Block Diagram



Function Table

Letter	Description
H	High-Level
L	Low-Level
X	Unrelated
Z	High Impedance
NC	No Connection

Table 1. Driver Function Table

Power		Input		Output	
V_{DD1}	V_{DD2}	DE	TXD	A	B
On	On	H	H	H	L
On	On	H	L	L	H
On	On	L	X	Z	Z
On	Off	X	X	Z	Z
Off	Off	L	L	Z	Z
Off	Off	X	X	Z	Z

Table 2. Receiver Function Table

Power		Input		Output
V_{DD1}	V_{DD2}	A−B (V)	$\overline{RE}$	RxD
On	On	≥−0.02	L or NC	H
On	On	≤−0.22	L or NC	L
On	On	−0.22 < A − B < −0.02	L or NC	Indeterminate
On	On	OPEN	L or NC	H
On	Off	X	L or NC	H
Off	Off	X	L or NC	L

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Pin Descriptions

Pin Number	Pin Name	Pin Functions
1	VDD1	Power Supply(Logic side)
2	GND1	Ground(Logic side)
3	RXD	Receiver Output Data
4	$\overline{RE}$	Receiver Enable Input. When $\overline{RE}$ is low, if (A−B) ≥ −20 mV, then RxD = high. If (A−B) ≤ −220 mV, then RxD = low.
5	DE	Driver Enable Input. When DE is high, outputs are enabled. When DE is low, outputs are high impedance. Drive DE low and $\overline{RE}$ high to enter shutdown mode.
6	TXD	Driver Input
7	GND1	Ground(Logic side)
8	GND1	Ground(Logic side)
9	GND2	Ground (Bus Side)
10	GND2	Ground (Bus Side)
11	NC	No Connect
12	A	RS485 Bus A Line
13	B	RS485 Bus B Line
14	NC	No Connect
15	GND2	Ground (Bus Side)
16	VDD2	Power Supply (Bus Side)

Absolute Maximum Ratings

General test conditions: Free-air, normal operating temperature range (unless otherwise specified).

PARAMETERS	UNIT
V_{DD1}	−0.5 V to +7 V
V_{DD2}	−0.5 V to +6 V
Digital Input Voltage (DE, $\overline{RE}$, TXD)	-0.3V to +6V
Digital Output Voltage (RxD)	-0.3V to +6V
Driver Output / Receiver input Voltage	−8 V to +13 V
Operating Temperature Range	−40°C to +105°C
Storage Temperature Range	−50°C to +125°C
Reflow Soldering Temperature	Peak temp. ≤260℃, maximum duration ≤60s at 217℃. Please also refer to IPC/JEDEC J-STD-020D.3.

Important: Exposure to Absolute Maximum Rated conditions for an extended period may severely affect the device reliability, and stress levels exceeding the “Absolute Maximum Ratings” may result in permanent damage.

Recommended Operating Conditions

Recommended Operating Conditions		Min.	Typ.	Max.	Unit
V_{DD1}	Logic Power Supply	2.375	3.3	5.5	V
V_{DD2}	Bus Power Supply	4.5	5	5.5	
V_{OC}	Voltage at any bus terminal (differential or common mode)	-7		12	
V_{IH}	High-level input voltage(TXD, DE, $\overline{RE}$)	2		V_{DD1}	
V_{IL}	Low-level input voltage(TXD, DE, $\overline{RE}$)	0		0.8	
V_{ID}	Differential input voltage	-7		+12	
R_L	Differential output load resistance	54	60		Ω
	Signaling rate			20	Mbps

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Electrical Characteristics

General test conditions and V_{DD1}=V_{DD2}= 5V, Ta = 25℃ (unless otherwise specified).

PARAMETERS		CONDITIONS		Min.	Typ.	Max.	Unit
DRIVER							
$\|V_{OD}\|$	Differential Driver Output	R_L = ∞, Figure 9				5	V
		R_L = 27 Ω (RS-485), Figure 9, 1Mbps		1.5		5	V
		R_L = 27 Ω (RS-485), Figure 9, 20Mbps		1.5		5.5	V
		V_{TEST} = −7 V to +12 V, V_{DD1} ≥ 4.75, Figure 10		1.5		5	V
$\Delta\|V_{OD}\|$	Δ $\|V_{OD}\|$ for Complementary Output States	R_L = 27 Ω , Figure 9				0.2	V
$V_{OC(SS)}$	Common-Mode Output Voltage	Figure 10				3	V
$\Delta V_{OC(SS)}$	Δ $\|V_{OC}\|$ for Complementary Output States	Figure 10				0.2	V
I_{OS}	Output Short-Circuit Current	-7V≤V_A or V_B≤12V			±110	±250	mA
V_{IH}	Input High Voltage	TXD, DE, $\overline{RE}$		2			V
V_{IL}	Input Low Voltage	TXD, DE, $\overline{RE}$				0.8	V
R_{TXD}	Internal TXD Pull up Resistor				9.1		kΩ
R_{DE}, $R_{\overline{RE}}$	Internal DE, $\overline{RE}$ Pull down Resistor				9.1		kΩ
RECEIVER							
$V_{IT(+)}$	Positive Differential Input Threshold Voltage	−7 V ≤ V_A or V_B ≤ +12 V				–20	mV
$V_{IT(-)}$	Negative Differential Input Threshold Voltage	−7 V ≤ V_A or V_B ≤ +12 V		–220			mV
V_{hys}	Hysteresis Voltage (V_{IT+} – V_{IT-})	−7 V ≤ V_A or V_B ≤ +12 V			20		mV
R_{ID}	Differential Input Resistance(A,B)	−7 V ≤ V_A or V_B +12 V		96			kΩ
I_I	Input Current (A, B)	DE=0, $\overline{RE}$=0	V_I=12V		190	250	uA
			V_I = -7V	-200	-110		uA
V_{OH}	RXD Output High Voltage	I_{OUT} = 20 μA, V_A − V_B = 0.2 V		V_{DD1} − 0.1			V
		I_{OUT} = 4 mA, V_A − V_B = 0.2 V		V_{DD1} − 0.4	V_{DD1} − 0.2		V
V_{OL}	RXD Output Low Voltage	I_{OUT} = −20 μA, V_A − V_B = 0.2 V				0.1	V
		I_{OUT} = −4 mA, V_A − V_B = 0.2 V				0.4	V
Supply and Protection							
I_{DD1}	Supply Current(Logic side)	4.5 V ≤ V_{DD1} ≤ 5.5 V, No load, $\overline{RE}$ = 0 V				4.5	mA
		3.0 V ≤ V_{DD1} ≤ 3.6 V, No load, $\overline{RE}$ = 0 V				4.5	mA
I_{DD2}	Supply Current(Bus side)	No load, DE = 5 V				6	mA
		No load, DE = 0 V				6	mA
ESD	HBM	A, B and GND				±15	kV
		Other pins				±2	kV
	IEC/EN 61000-4-2 (Contact) Perf. Criteria B	A, B and GND				±4	kV
EFT	IEC61000-4-4 : Perf. Criteria B	A, B and GND				±2	kV
Surge	IEC61000-4-5 : Perf. Criteria B	A, B and GND(Common Mode)				±2	kV
V_{I-O}	Isolation Test	Leakage current <1mA.				3750	Vrms
R_{I-O}	Insulation Resistance	At 500VDC		1000			MΩ
C_{I-O}	Isolation capacitor				3		pF
CMTI	Common Mode Transient Immunity	TXD = V_{DD1} or 0 V, VCM = 1 kV, transient magnitude = 800 V		25			kV/μs

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Transmission Characteristics

General test conditions and V_{DD1}=V_{DD2} = 5V, Ta = 25℃ (unless otherwise specified).

PARAMETERS		CONDITIONS	Min.	Typ.	Max.	Unit
	Maximum Data Rate				20	Mbps
DRIVER(Test conditions: 25℃, transmission rate =1Mbps)						
t_{PLH}, t_{PHL}	Propagation Delay	R_L = 54 Ω, C_{L1} = C_{L2} = 100 pF, Figure11		40	110	ns
t_{SKEW}	Skew (|T_{PHL} - T_{PLH}|)				40	ns
tr, tf	Rise/Fall Time			50	120	ns
RECEIVER(Test conditions: 25℃, transmission rate =1Mbps)						
t_{PLH}, t_{PHL}	Propagation Delay	C_L = 15 pF, Figure12		60	110	ns
t_{SKEW}	Differential Skew (|T_{PLH} - T_{PHL}|)				250	ns
DRIVER(Test conditions: 25℃, transmission rate = 20Mbps)						
t_{PLH}, t_{PHL}	Propagation Delay	R_L = 54 Ω, C_{L1} = C_{L2} = 100 pF, Figure11		30	60	ns
t_{SKEW}	Skew (|T_{PHL} - T_{PLH}|)				15	ns
tr, tf	Rise/Fall Time				60	ns
RECEIVER(Test conditions: 25℃, transmission rate = 20Mbps)						
t_{PLH}, t_{PHL}	Propagation Delay	C_L = 15 pF, Figure12		60	150	ns
t_{SKEW}	Differential Skew (|T_{PLH} - T_{PHL}|)				20	ns
tr, tf	Bus rise/fall time			25		ns

Physical Specifications

PARAMETERS	Value	Unit
Weight	0.4(Typ.)	g

Typical Performance Curves

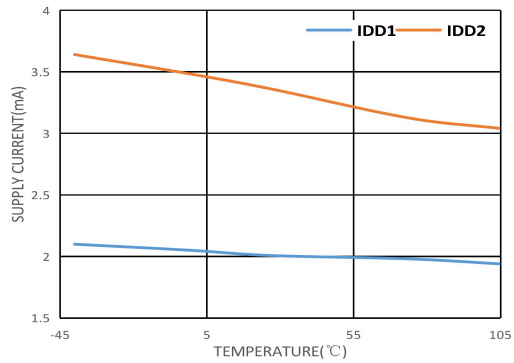


Figure3. Unloaded Supply Current vs. Temperature

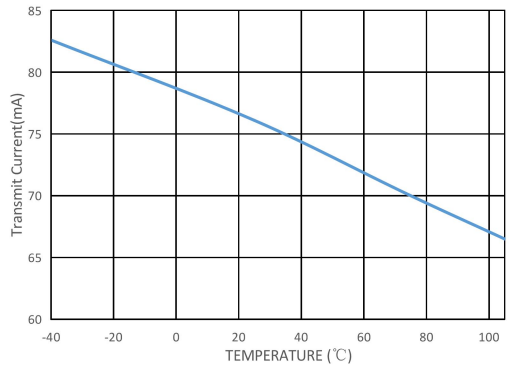


Figure4. Transmit Current vs. Temperature, VDD1=5V, VDD2=5V

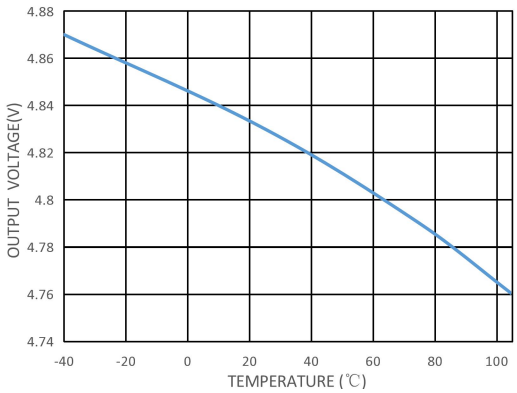


Figure5. Receiver Output High Voltage vs. Temperature

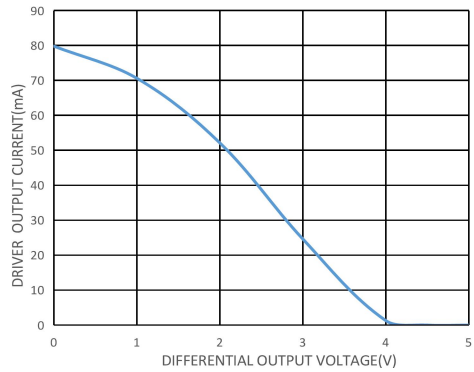


Figure6. Driver Output Current vs. Differential Output Voltage

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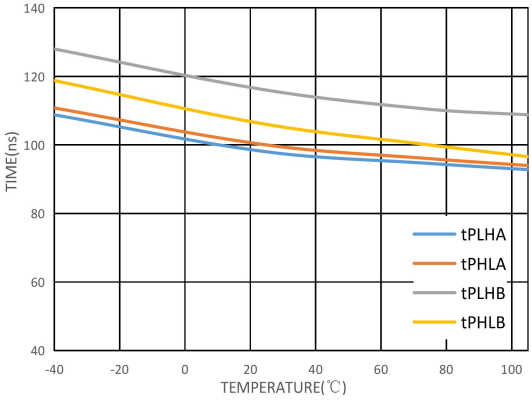


Figure7. Driver Progation Delay vs. Temperature

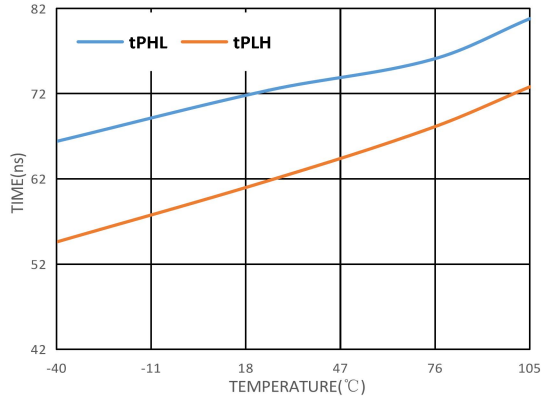


Figure 8. Receiver Progation Delay vs. Temperature

Test Circuits

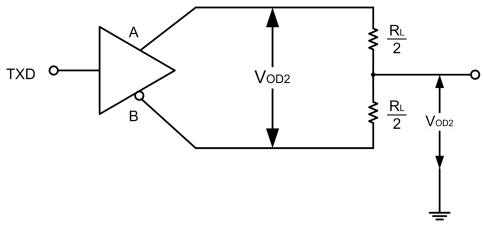


Figure 9. Driver Test Circuit

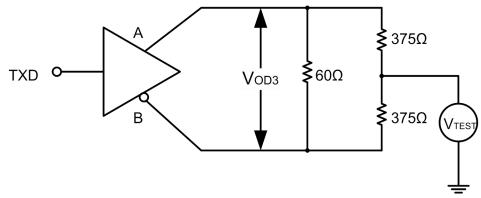


Figure 10. Driver Test Circuit, VOD With Common-Mode Loading

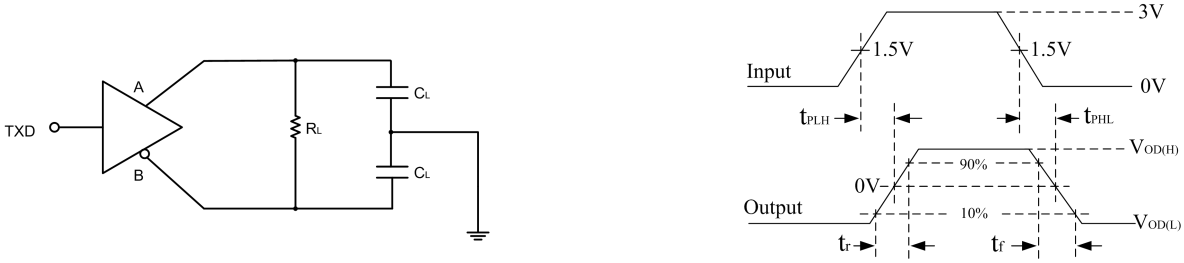


Figure 11. Drive propagation delay test circuit and wave forms

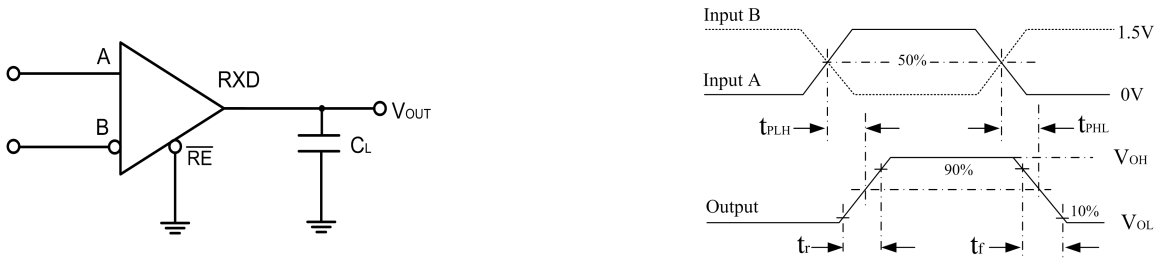


Figure 12. Receiver propagation delay test circuit and wave forms

Detailed Description

TD041S485H is an advanced RS-485 transceivers. They each contain one driver and one receiver. These devices feature a fail-safe circuitry that guarantees a high receiver output voltage when the receiver inputs are either open, shorted or when they are connected to a terminated transmission line with all drivers disabled. TD041S485H operates with a two power supply. Their logic side supports 3.3V and 5V logic level conversion. The whole machine can monitor the overall working state of the module and limit the output high current to prevent the bus from overload or short circuit causing unrecoverable damage to the transceiver.

Receiver input filter: TD041S485H receiver have an integrated input filter which enhances noise immunity of the high-speed differential signals. The receiver propagation delay increases due to this filtering.

Bus fail-safe: Ordinary RS485 bus receivers will be in an indeterminate state when -220mV< A - B <-20mV. This situation can occur whenever the data bus is not being actively driven. The advanced Fail-safe feature of the TD041S485H guarantees a high receiver output voltage if the receiver's differential inputs are either shorted, open circuit, or if they are connected to a termination resistor.

The TD041S485H receiver thresholds are very precise, and the offset between threshold voltage and ground has a margin of at least 10mV. This guarantees that the receiver output is a high voltage even the input differential is zero volts, thus maintaining compliance with the EIA/TIA-485 standard.

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Load abilities on the bus (256 nodes): The standard receiver input impedance of RS-485 is 12kΩ (1 unit load). A standard RS485 driver can drive at least 32 unit loads. The TD(H)041S485H transceiver is designed to 1/8th of the standard unit load and the input impedance is higher than 96kΩ, hence allowing up to 256 unit loads. The TD(H)041S485H can work combined with other standard RS485 that use the smaller amount of unit loads.

Low power shutdown mode: A low-power shutdown mode is triggered by simultaneously bringing high and DE low. During shutdown mode the device supply current is 6mA typical. DE and can be directly connected and controlled by the same I/O. The devices are guaranteed not to enter shutdown mode if is high and DE is low for less than 50ns. If this state is maintain for at least 600ns, the device will shutdown reliably.

Driver output protection: The device prevents excessive output current caused by fault conditions or driver short circuit. A driver current limit on the output stage provides and ensures immediate protection against short circuits over the entire common mode voltage range.

Application circuit

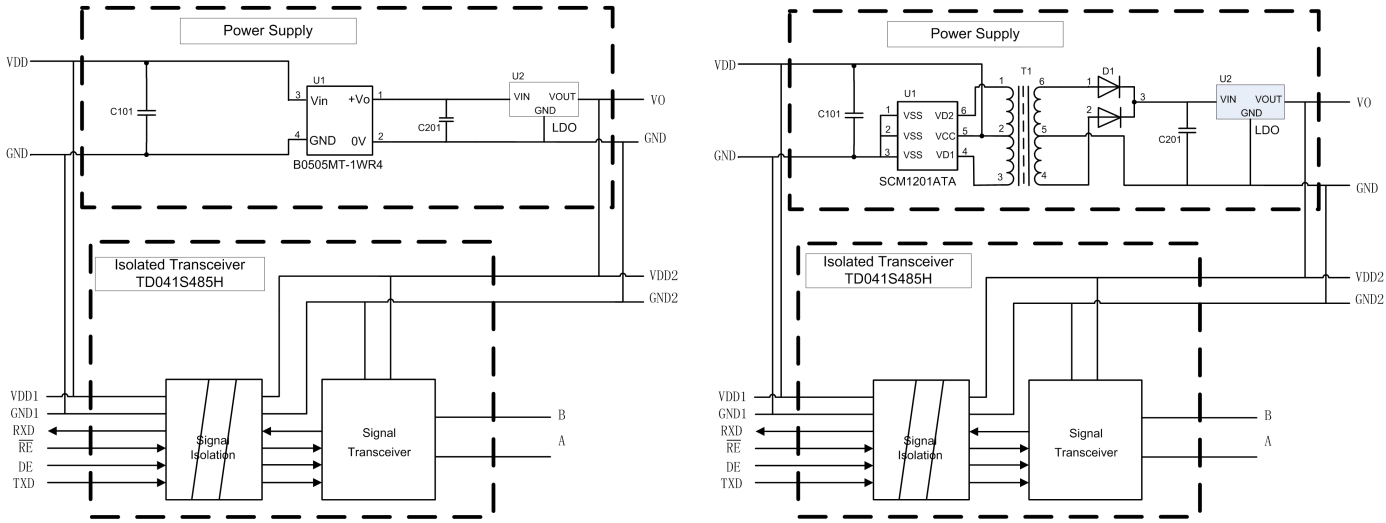


Figure 13. Receiver propagation delay test circuit and wave forms

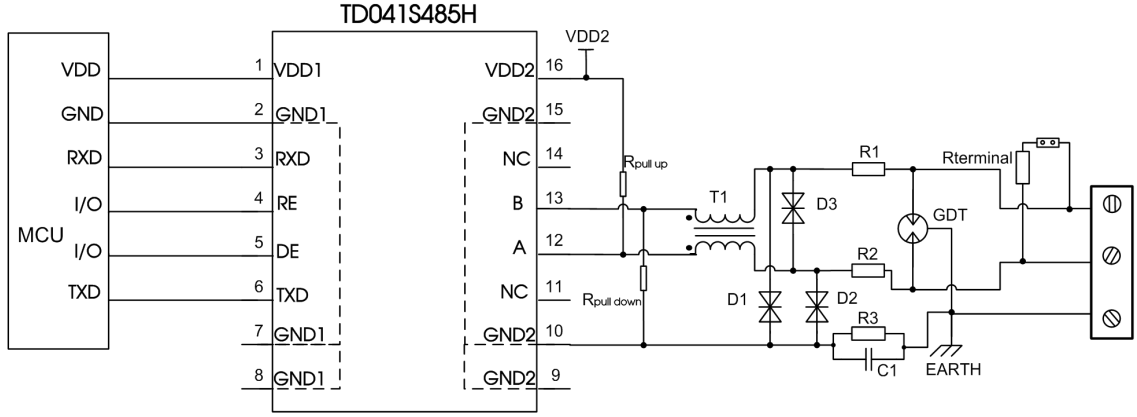


Figure14. Port protection circuit for harsh environments

Recommended components and values:

Component	Recommended part, value	Component	Recommended part, value
R3	1MΩ	R1, R2	2.7Ω/2W
C1	1nF, 2kV	D1, D2	SMBJ6.5CA
T1	ACM2520-301-2P	D3	SMBJ6.5CA
GDT	B3D090L	$R_{terminal}$	120Ω

As the modules internal A / B lines come with its own ESD protection, which generally satisfy most application environments without the need for additional ESD protection devices. For harsh and noisy application environments such as motors, high voltage/current switches, lightning and similar however, we recommended that the user protects the module's A / B lines with additional measures and external components such as TVS tube, common mode inductors, Gas discharge tube, shielded twisted pair of wires with the same single network Earth point. Figure 14 shows our recommended circuit diagram for such type of applications with components and values given in the table above. This recommendation is for reference only and may have to be adapted accordingly with appropriate component values in order to match the actual situation and application.

Note: Select the $R_{terminal}$ according to the actual application.

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Using Suggests

① Hot-swap is not supported.

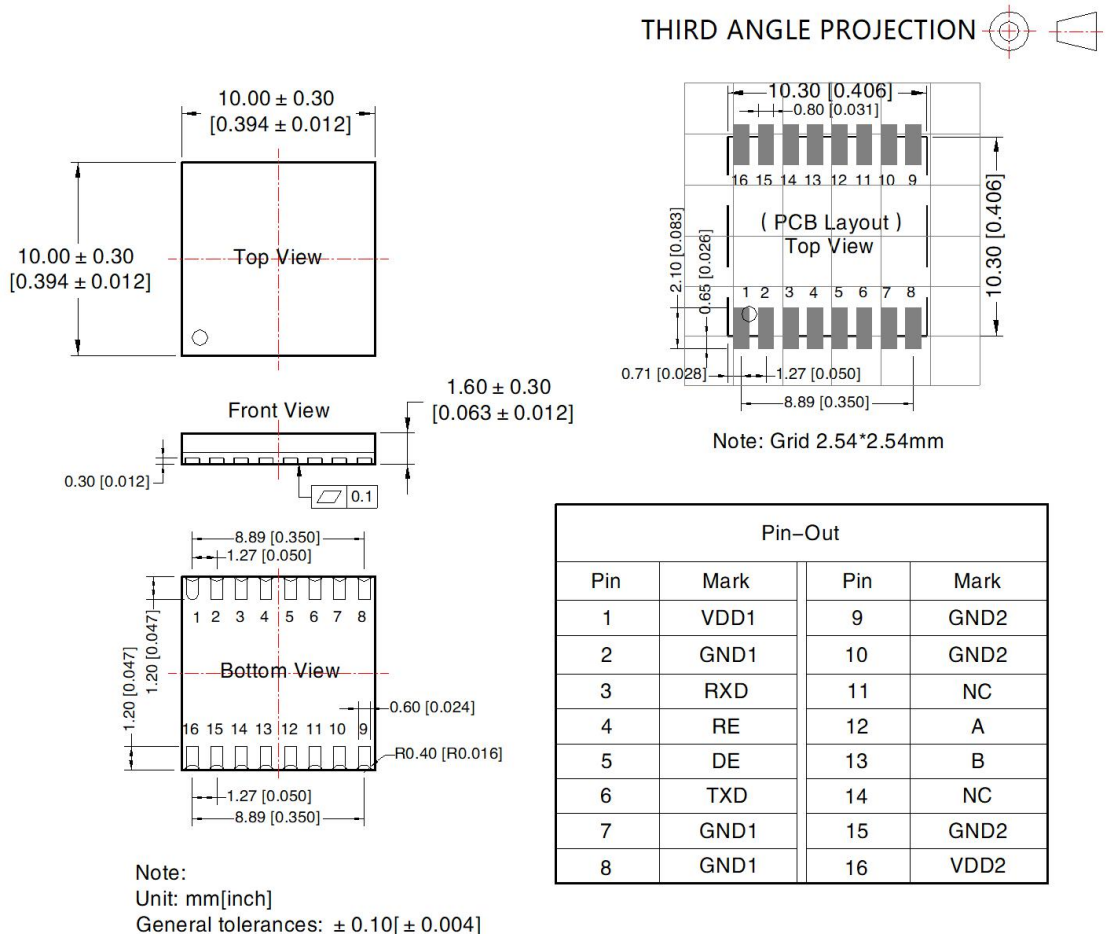
② If the external input of TXD is insufficient, the pull-up resistor should be added according to the situation.

③ Refer to *IPC 7093* for the welding process design of this product. For detailed operation guidance, please refer to *Hot Air Gun Welding Operation Instruction for DFN Package Product* or *Welding Operation Instruction for DFN Package Product*.

Ordering Information

Part number	Package	Number of pins	Product Marking	Tape & Reel
TD041S485H	DFN	16	TD041S485H	500/REEL

Package Information(DNF-16)

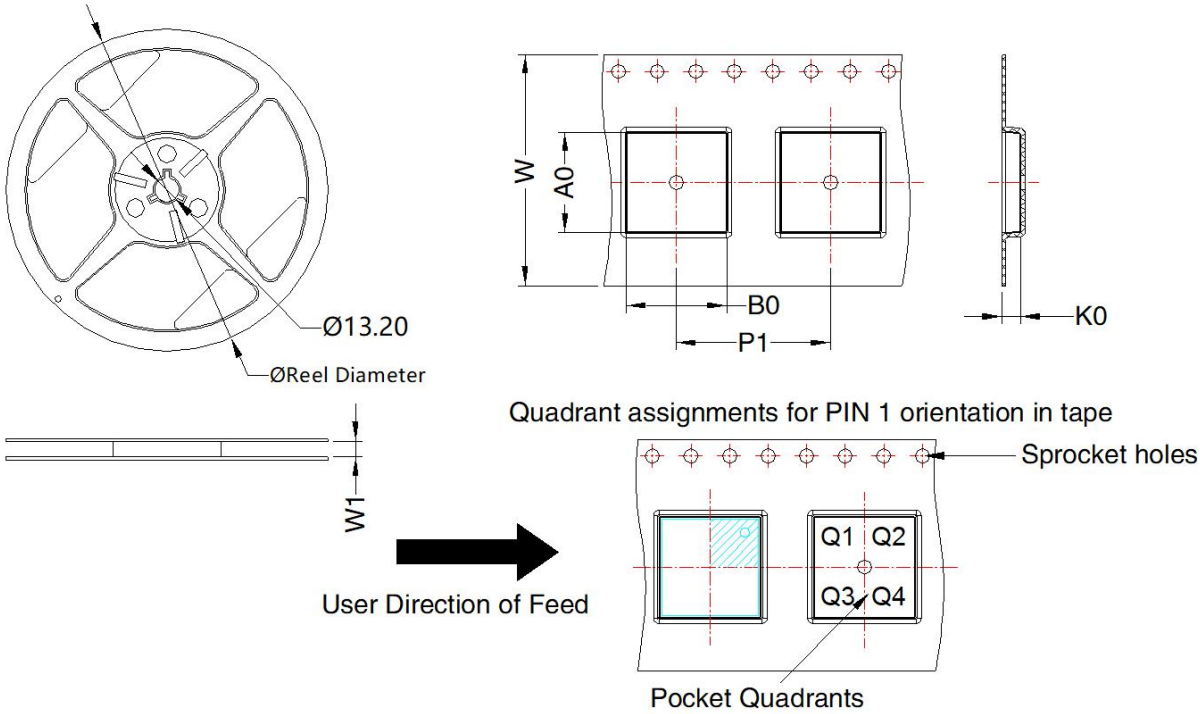


Note: Grid 2.54*2.54mm

Note:
Unit: mm[inch]
General tolerances: ± 0.10[± 0.004]

Pin–Out			
Pin	Mark	Pin	Mark
1	VDD1	9	GND2
2	GND1	10	GND2
3	RXD	11	NC
4	RE	12	A
5	DE	13	B
6	TXD	14	NC
7	GND1	15	GND2
8	GND1	16	VDD2

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Device	Package Type	Pin	MPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TD(H)041S485H	DFN 10x10	16	500	180.0	24.4	10.44	10.44	2.0	16.0	24.0	Q2

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